Near-unity Photoluminescence Quantum Yield (QY) in Monolayer Semiconductors by Electrostatic Doping

Shiekh Zia Uddin

Theme I

PI: Ali Javey **Collaborator:** Eli Yablonovitch, Ming Wu





Background: Photoluminescence Quantum Yield in MoS₂



• MoS₂ monolayer shows near-unity PL QY after TFSI treatment.

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• The first time recognizing the pump-dependent excitonic nature in 2D semiconductors.



M. Amani, D. H. Lien, D. Kiriya, et al, Science, 350, 1065-1068, 2015





Excitons and Trions in Monolayer MoS₂

Neutral exciton



Effect of TFSI is Electron Counterdoping



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PL QY as a Function of Gate Voltage and Pump



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Conclusions and Future Directions



Recombination of neutral exciton is **entirely radiative** even in the presence of a **high native defect density**.

Light emitting region in TMDC devices has to be undoped.



Future direction:

- How to suppress biexciton annihilation?
- Is it applicable to other excitonic systems?





Thank You

Javey Lab Members: Der-Hsien Lien Hyungjin Kim Matthew Yeh Matin Amani Shiekh Zia Uddin









Supporting Slide 1: Kinetic Model



Supporting Slide 2: Kinetic Model



$$G = \left(\frac{1}{\tau_{Xr}} + \frac{1}{\tau_{Xnr}}\right) n_X + \left(\frac{1}{\tau_{Tr}^-} + \frac{1}{\tau_{Tnr}^-}\right) n_T^- + C_{bx} n_X^2 = \frac{n_X}{\tau_X} + \frac{n_T^-}{\tau_T^-} + C_{bx} n_X^2$$
$$QY = \frac{1}{G} \left(\frac{n_X}{\tau_{Xr}} + \frac{n_T^-}{\tau_{Tr}^-} + \frac{n_T^+}{\tau_{Tr}^+}\right)$$

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Supporting Slide 3: Why PMMA







Supporting Slide 4: PL Peak Shift







Supporting Slide 5: TRPL





